



## ADCMP361

### FEATURES

- 400 mV  $\pm$  0.275% threshold
- Supply range: 1.7 V to 5.5 V
- Low quiescent current: 6.5  $\mu$ A typical
- Input range includes ground
- Internal hysteresis: 9.3 mV typical
- Low input bias current:  $\pm$ 5 nA maximum
- Dual open-drain outputs
- Small SOT-23 package

### APPLICATIONS

- Li-Ion monitoring
- Threshold detectors
- Relay driving
- Optoisolator driving
- Industrial control systems
- Handheld instruments

### GENERAL DESCRIPTION

The ADCMP361 is a single low power, high accuracy comparator with a 400 mV reference in a 5-lead SOT-23 package. The internal 400 mV reference provides the ability to monitor low voltage supplies. The device operates on a supply voltage from 1.7 V to 5.5 V and only draws 6.5  $\mu$ A typical, making it suitable for low power system monitoring and portable applications. Hysteresis is included in the comparators.

There are dual open-drain outputs to enable the comparator and reference circuit to be used in an inverting or noninverting configuration. The outputs can be pulled to any voltage up to a maximum of 5.5 V. The output stage is guaranteed to sink greater than 5 mA over temperature

The device is suitable for portable, commercial, industrial, and automotive applications.

### FUNCTIONAL BLOCK DIAGRAM

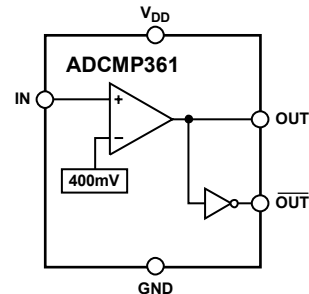


Figure 1.

06498-001

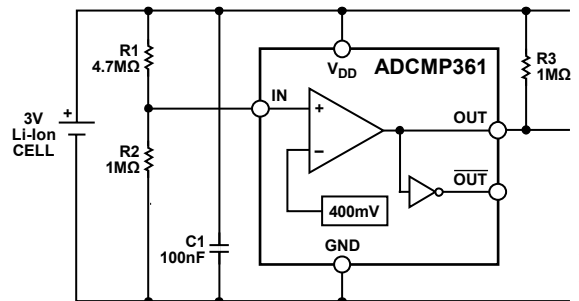


Figure 2. Typical Li-Ion Monitoring Application

06498-029

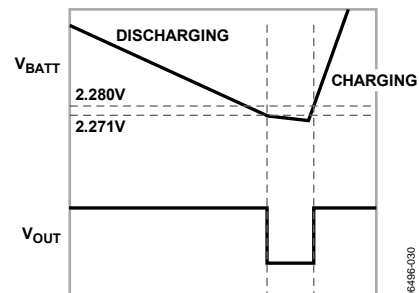


Figure 3. Li-Ion Monitoring Waveforms

06498-030

### Rev. 0

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## REVISION HISTORY

2/07—Revision 0: Initial Version

## SPECIFICATIONS

$V_{DD} = 1.7\text{ V to }5.5\text{ V}$ ,  $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Min	Typ	Max	Unit	Test Conditions/Comments
<b>THRESHOLDS<sup>1</sup></b>					
Rising Input Threshold Voltage	399.3	400.4	401.5	mV	$V_{DD} = 3.3\text{ V}$ , $T_A = 25^{\circ}\text{C}$
	391.2	400.4	407.7	mV	$V_{DD} = 1.7\text{ V}$
	393.1	400.4	405.9	mV	$V_{DD} = 3.3\text{ V}$
	393.1	400.4	405.8	mV	$V_{DD} = 5.5\text{ V}$
Falling Input Threshold Voltage	381.1	391.1	400.9	mV	$V_{DD} = 1.7\text{ V}$
	381.2	391.1	398.4	mV	$V_{DD} = 3.3\text{ V}$
	381.0	391.1	398.2	mV	$V_{DD} = 5.5\text{ V}$
Hysteresis = $V_{TH(R)} - V_{TH(F)}$	2	9.3	13.5	mV	
Threshold Voltage Accuracy			$\pm 0.275$	%	$T_A = 25^{\circ}\text{C}$ , $V_{DD} = 3.3\text{ V}$
Threshold Voltage Temperature Coefficient		16		ppm/ $^{\circ}\text{C}$	
<b>POWER SUPPLY</b>					
Supply Current		6.5	9	$\mu\text{A}$	$V_{DD} = 1.7\text{ V}$
		7.0	10	$\mu\text{A}$	$V_{DD} = 5.5\text{ V}$
<b>INPUT CHARACTERISTICS</b>					
Input Bias Current		0.01	5	nA	$V_{DD} = 1.7\text{ V}$ , $V_{IN} = V_{DD}$
		0.01	5	nA	$V_{DD} = 1.7\text{ V}$ , $V_{IN} = 0.1\text{ V}$
<b>OPEN-DRAIN OUTPUTS</b>					
Output Low Voltage <sup>2</sup>		140	220	mV	$V_{DD} = 1.7\text{ V}$ , $I_{OUT} = 3\text{ mA}$
		140	220	mV	$V_{DD} = 5.5\text{ V}$ , $I_{OUT} = 5\text{ mA}$
Output Leakage Current <sup>3</sup>		0.01	1	$\mu\text{A}$	$V_{DD} = 1.7\text{ V}$ , $V_{OUT} = V_{DD}$
		0.01	1	$\mu\text{A}$	$V_{DD} = 1.7\text{ V}$ , $V_{OUT} = 5.5\text{ V}$
<b>DYNAMIC PERFORMANCE</b>					
High-to-Low Propagation Delay <sup>2,4</sup>		10		$\mu\text{s}$	$V_{DD} = 5\text{ V}$ , $V_{OL} = 400\text{ mV}$
Low-to-High Propagation Delay <sup>2,4</sup>		8		$\mu\text{s}$	$V_{DD} = 5\text{ V}$ , $V_{OH} = 0.9 \times V_{DD}$
Output Rise time <sup>2,4</sup>		0.5		$\mu\text{s}$	$V_{DD} = 5\text{ V}$ , $V_O = (0.1\text{ to }0.9) \times V_{DD}$
Output Fall time <sup>2,4</sup>		0.07		$\mu\text{s}$	$V_{DD} = 5\text{ V}$ , $V_O = (0.1\text{ to }0.9) \times V_{DD}$

<sup>1</sup>  $R_L = 100\text{ k}\Omega$ ,  $V_O = 2\text{ V}$  swing.

<sup>2</sup> 10 mV input overdrive.

<sup>3</sup>  $V_{IN} = 40\text{ mV}$  overdrive.

<sup>4</sup>  $R_L = 10\text{ k}\Omega$ .

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## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
V <sub>DD</sub>	−0.3 V to +6 V
IN	−0.3 V to +6 V
OUT, $\overline{\text{OUT}}$	−0.3 V to +6 V
Operating Temperature Range	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature	
Soldering (10 sec)	300°C
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL CHARACTERISTICS

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	$\theta_{JA}$	Unit
5-Lead SOT-23	240	°C/W

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

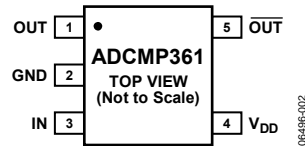


Figure 4. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	OUT	Noninverting Open-Drain Output.
2	GND	Ground.
3	IN	Monitors analog input voltage on comparator. The other input of the comparator is connected to a 400 mV reference.
4	V <sub>DD</sub>	Power Supply.
5	$\overline{\text{OUT}}$	Inverting Open-Drain Output.

## TYPICAL PERFORMANCE CHARACTERISTICS

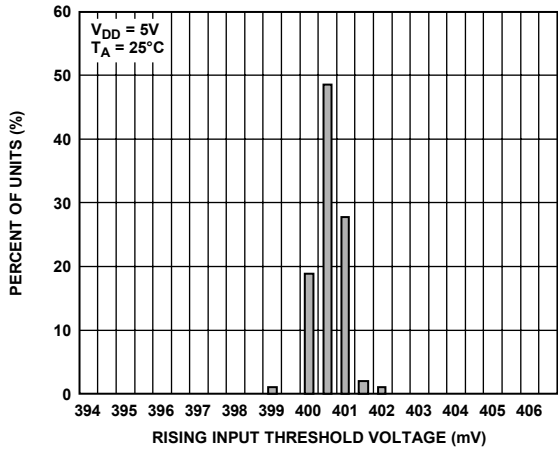


Figure 5. Distribution of Rising Input Threshold Voltage

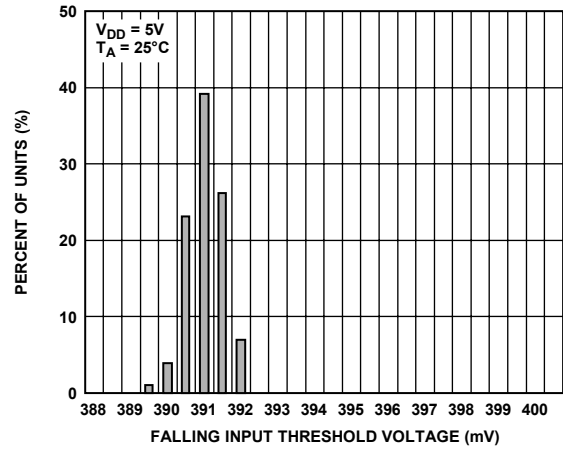


Figure 8. Distribution of Falling Input Threshold Voltage

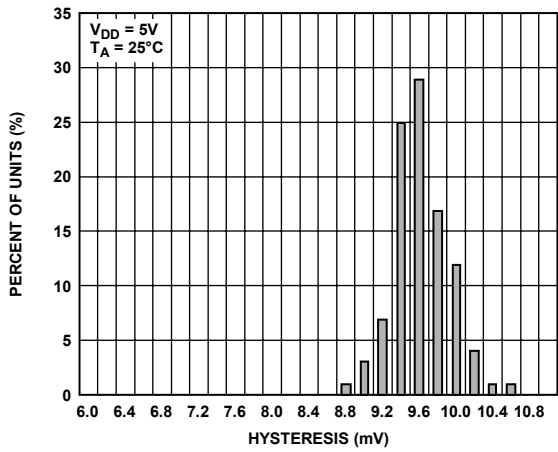


Figure 6. Distribution of Hysteresis

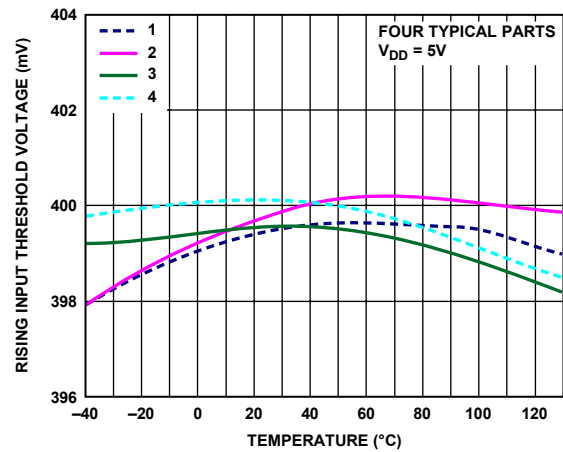


Figure 9. Rising Input Threshold Voltage vs. Temperature

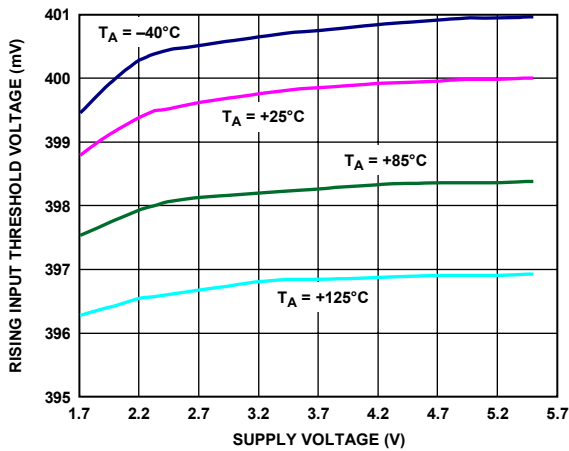


Figure 7. Rising Input Threshold Voltage vs. Supply Voltage

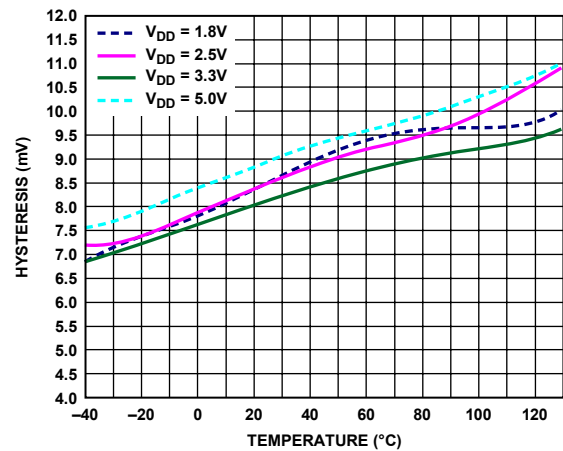


Figure 10. Hysteresis vs. Temperature

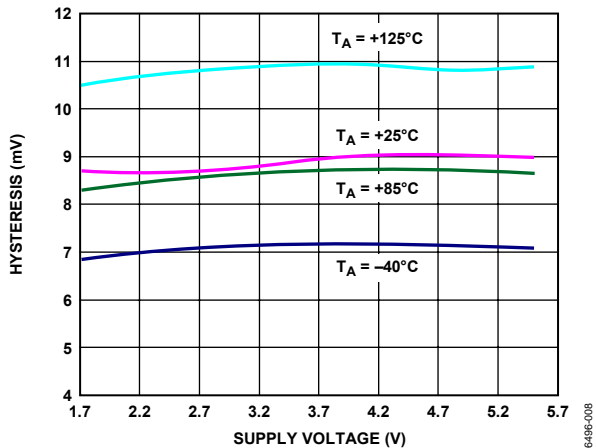


Figure 11. Hysteresis vs. Supply Voltage

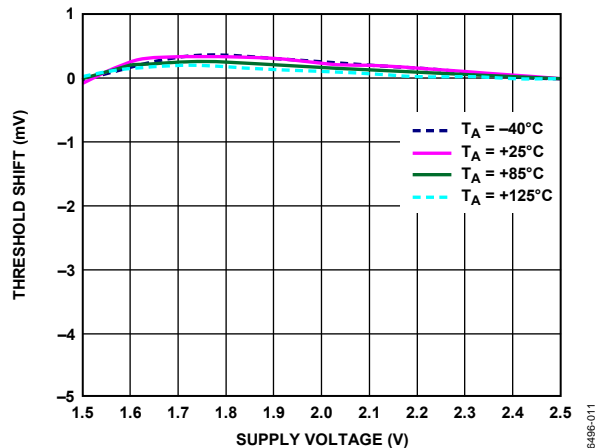


Figure 14. Minimum Supply Voltage

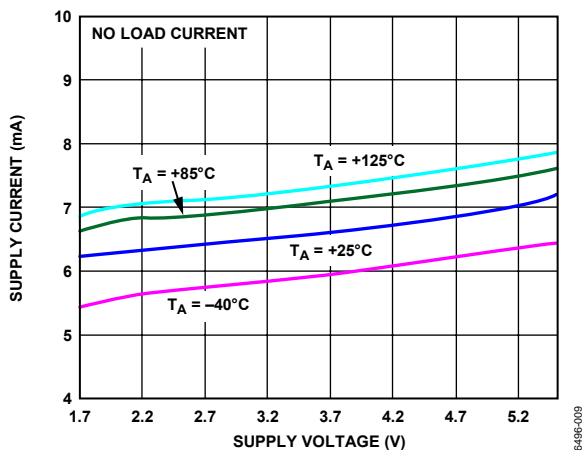


Figure 12. Quiescent Supply Current vs. Supply Voltage

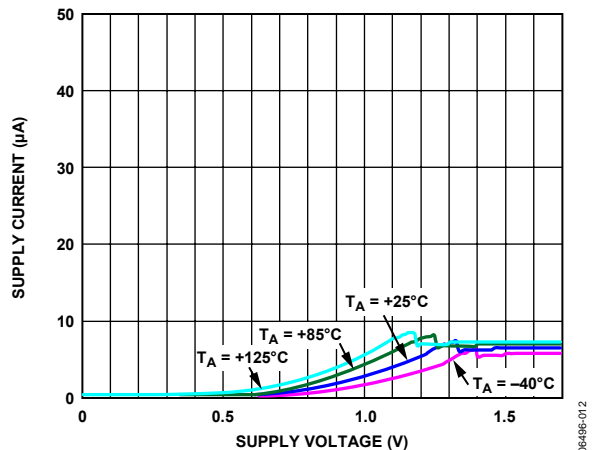


Figure 15. Start-Up Supply Current

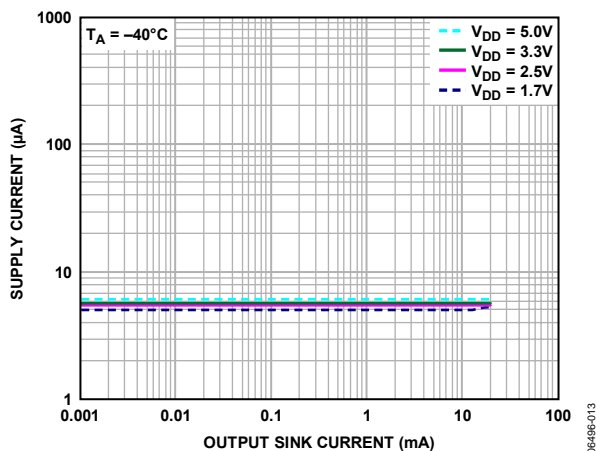


Figure 13. Supply Current vs. Output Sink Current

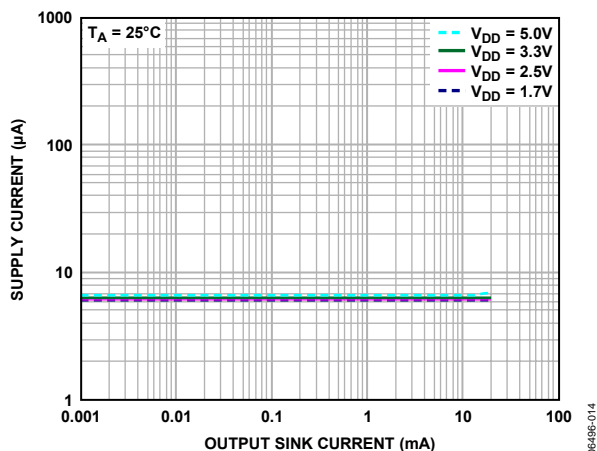


Figure 16. Supply Current vs. Output Sink Current

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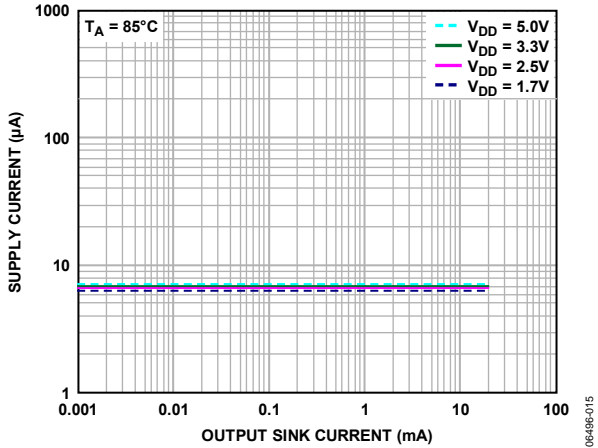


Figure 17. Supply Current vs. Output Sink Current

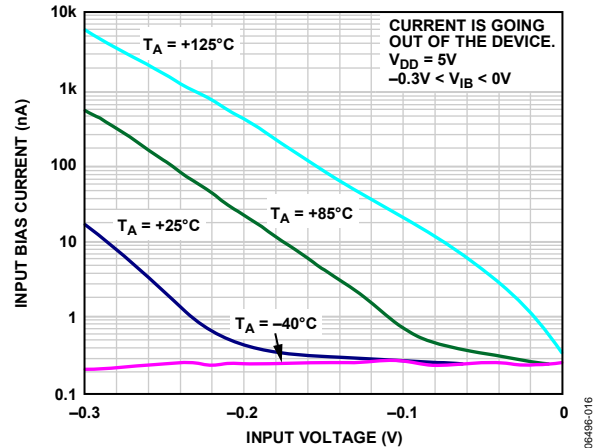


Figure 20. Below Ground Input Bias Current

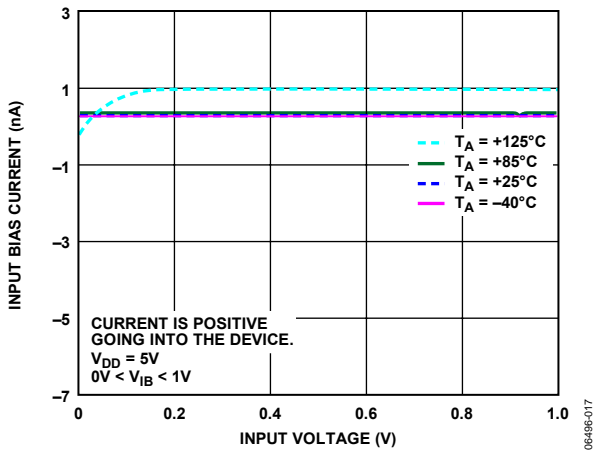


Figure 18. Low Level Input Bias Current

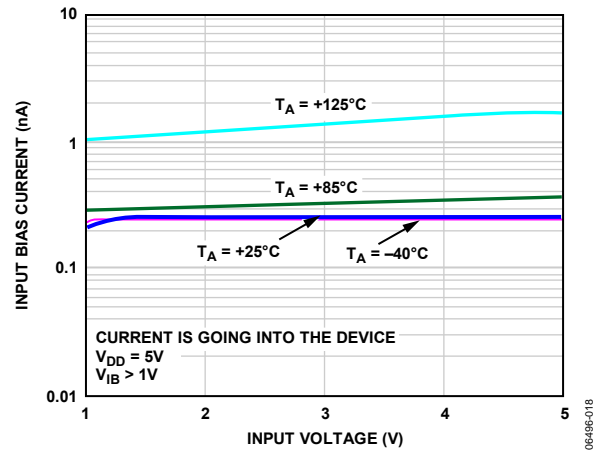


Figure 21. High Level Input Bias Current

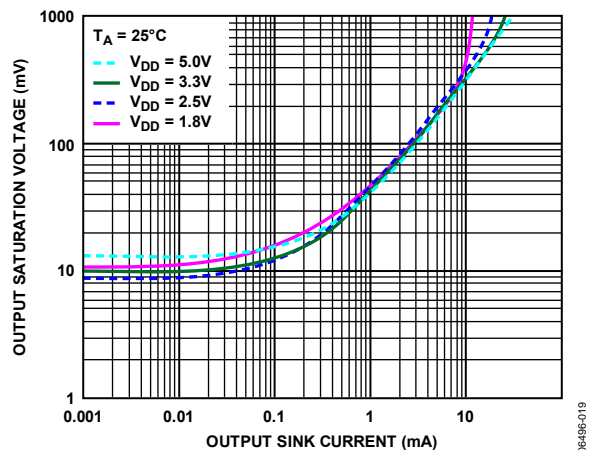


Figure 19. Output Saturation Voltage vs. Output Sink Current

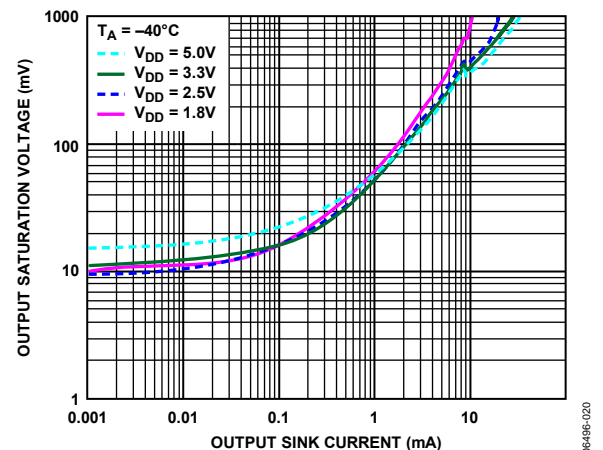


Figure 22. Output Saturation Voltage vs. Output Sink Current



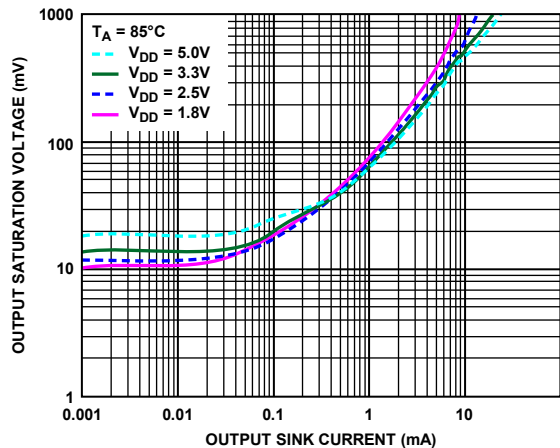


Figure 23. Output Saturation Voltage vs. Output Sink Current

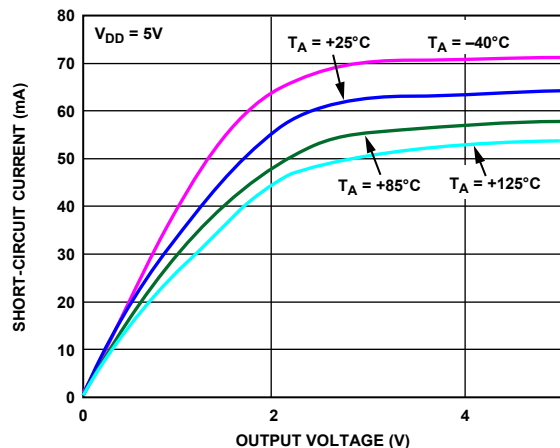


Figure 26. Short-Circuit Current vs. Output Voltage

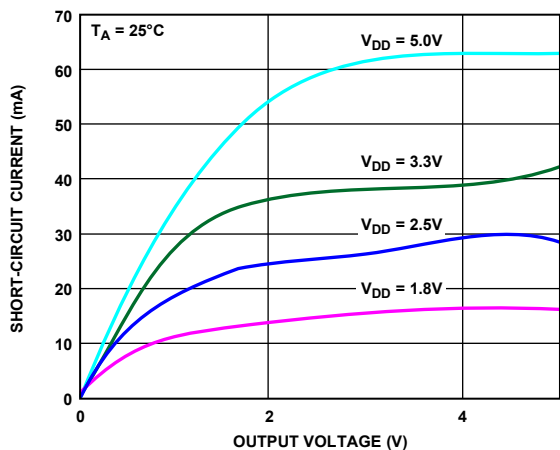


Figure 24. Short-Circuit Current vs. Output Voltage

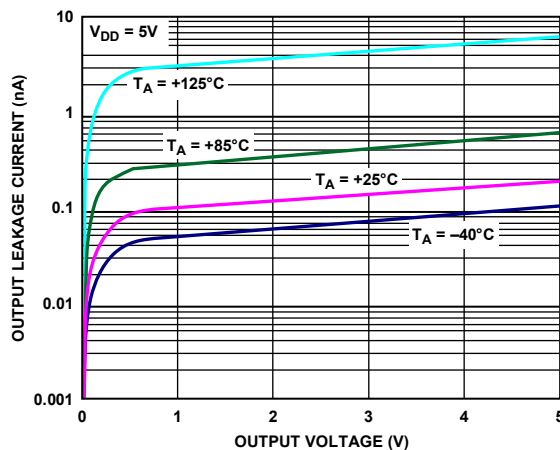


Figure 27. Output Leakage Current vs. Output Voltage

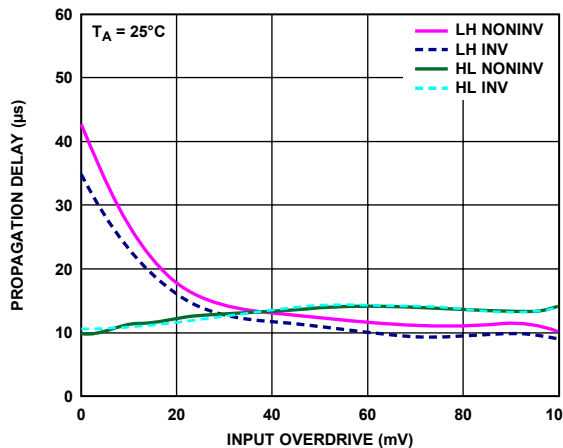


Figure 25. Propagation Delay vs. Input Overdrive

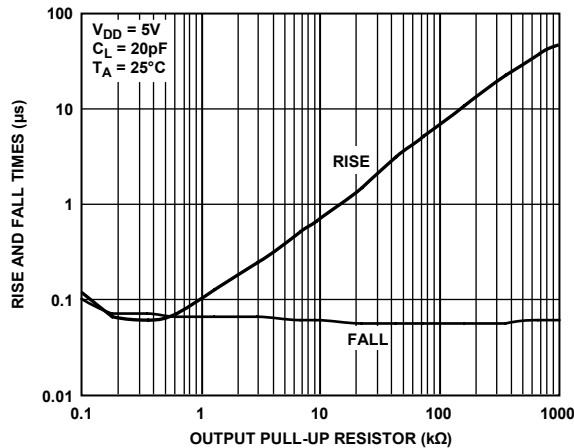


Figure 28. Rise and Fall Times vs. Output Pull-Up Resistor

# ADCMP361

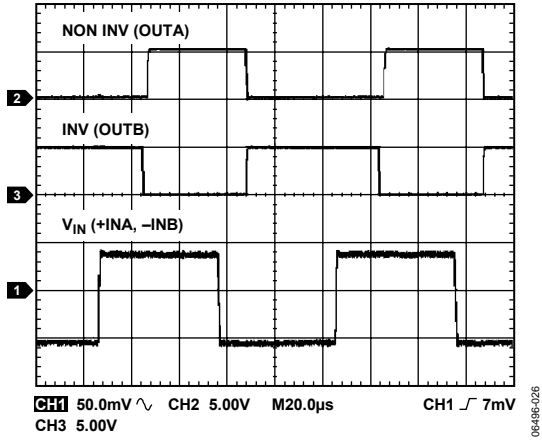


Figure 29. Noninverting and Inverting Comparators Propagation Delay

## APPLICATION INFORMATION

The ADCMP361 is a low power comparator and reference circuit featuring a 400 mV reference that operates from 1.7 V to 5.5 V. The comparator is 0.275% accurate with a built-in hysteresis of 9.3 mV. There are two outputs, one the inverse of the other. This enables the ADCMP361 to be used as an inverting or a noninverting comparator circuit. These open-drain outputs are capable of sinking 40 mA.

### COMPARATORS AND INTERNAL REFERENCE

The comparator has one input available externally; the other comparator input is connected internally to the 400 mV reference. The rising input threshold voltage of the comparators is designed to be equal to that of the reference.

### POWER SUPPLY

The ADCMP361 is designed to operate from 1.7 V to 5.5 V. A 100 nF decoupling capacitor is recommended between  $V_{DD}$  and GND.

### INPUTS

The comparator input is limited to the maximum  $V_{DD}$  voltage range. The voltage on these inputs can be above  $V_{DD}$  but never above the maximum allowed  $V_{DD}$  voltage. When adding a resistor string to the input, care must be taken when choosing resistor values. This is due to the fact that the input bias current will be in parallel with the bottom resistor, R2, of the input resistor divider string. This bottom resistor must therefore be chosen carefully in order to reduce the error introduced by this bias current (see Figure 30).

### OUTPUTS

The open-drain comparator outputs are limited to the maximum specified  $V_{DD}$  voltage range, regardless of the  $V_{DD}$  voltage. These outputs are capable of sinking up to 40 mA.

### ADDING HYSTERESIS

To prevent oscillations at the output caused by noise or slowly moving signals passing the switching threshold, each comparator has built-in hysteresis of approximately 9.3 mV. Positive feedback can be used to increase hysteresis.

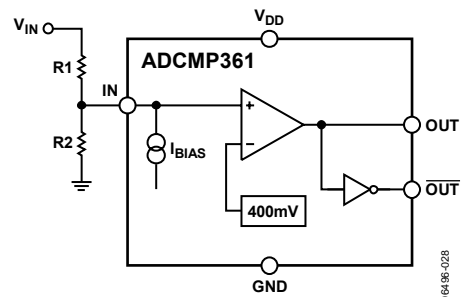
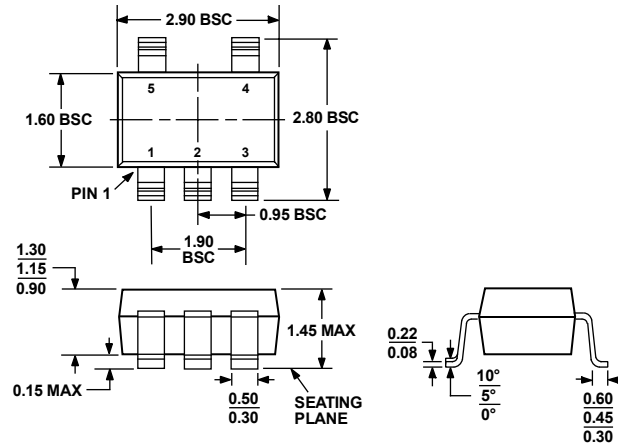


Figure 30. Input Bias Current Effect on Input Resistor String

# ADCMP361

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-178-AA

Figure 31. 5-Lead Small Outline Transistor Package [SOT-23] (RJ-5)

Dimensions shown in millimeters

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
ADCMP361YRJZ-REEL7 <sup>1</sup>	-40°C to +125°C	5-Lead SOT-23	RJ-5	M99

<sup>1</sup> Z = Pb-free part.